

# New properties and prospects for hot intraband luminescence

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ISMART, Minsk, October 11, 2018



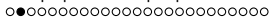
## 10-ps challenge

Goal:

Increase scintillation time resolution to **10 ps**

Applications:

- Time-of-flight positron emission tomography (TOF-PET)
- High-energy physics (pile-up events discrimination)
- X-ray imaging at GHz frame rate (XFEL, rapid processes, ...)
- Space telescopes: miniature time-of-flight neutron detectors

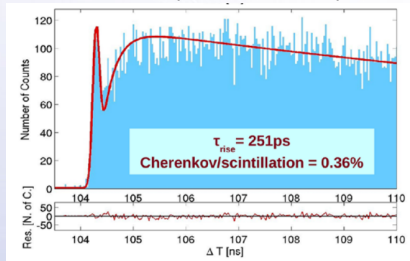


# Prompt photons concept for high-resolution TOF-PET

Scintillation under 511 keV  $\gamma$ -excitation (small crystals)

LuAG:Pr

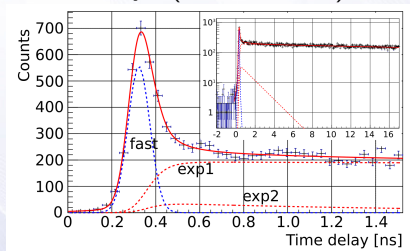
CTR **205 ps** ( $2 \times 2 \times 10 \text{ mm}^3$ )



[1] S. Gundacker et al, Phys. Med. Biol. 61 (2016) 2802

BGO

CTR **330 ps** ( $3 \times 3 \times 20 \text{ mm}^3$ )



[2] S E Brunner and D R Schaart Phys. Med. Biol. 62 (2017) 4421

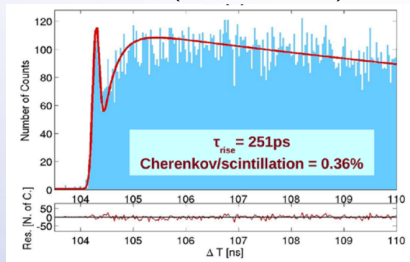


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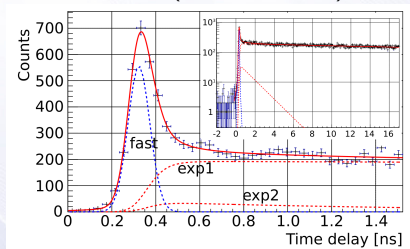
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BGO

CTR **330 ps** ( $3 \times 3 \times 20$  mm<sup>3</sup>)



Conventional scintillation record

LYSO:Ce,Ca: CTR **100 ps** ( $2 \times 2 \times 10$  mm<sup>3</sup>)



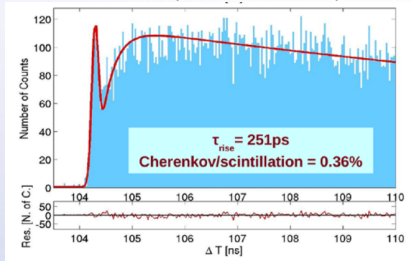


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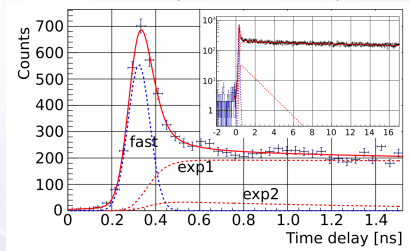
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BGO

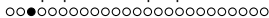
CTR **330 ps** ( $3 \times 3 \times 20 \text{ mm}^3$ )



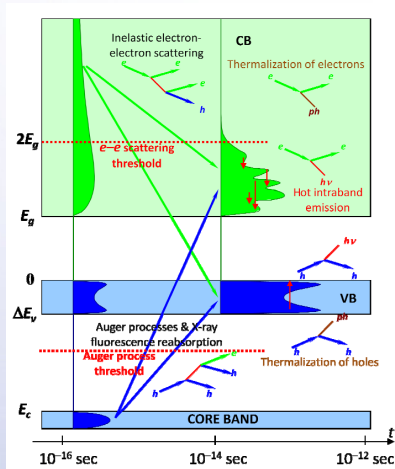
Conventional scintillation record

LYSO:Ce,Ca: CTR **100 ps** ( $2 \times 2 \times 10 \text{ mm}^3$ )

**Need more prompt photons!**



# Intraband luminescence (IBL) mechanism



- Decay  $10^{-12}$  s
- Broad structureless spectrum
- Yield determined by branching ratio  
(D. Vaisburd, 1980s):

$$\eta = \frac{P_{rad}}{P_{nonrad}} \approx \frac{\tau_{nonrad}}{\tau_{rad}} \approx \frac{1ps}{10ns} \approx 10^{-4} \rightarrow 10 \text{ ph/MeV}$$

The mechanism of IBL  
(drawing by A. Vasil'ev)

## The experimental facts about IBL in insulators

- Observed under excitation by (sub)nanosecond pulses of electrons and laser radiation

First publication:



D.I. Vaisburd et al. Izv. Nauk  
AS USSR. Phys. Ser. 38/6  
(1974) 1281-1284

# The experimental facts about IBL in insulators

- Observed under excitation by (sub)nanosecond pulses of electrons and laser radiation
- No excitation density threshold found

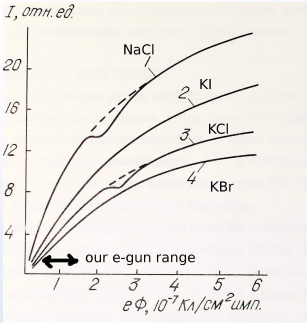
First publication:



D.I. Vaisburd et al. Izv. Nauk AS USSR. Phys. Ser. 38/6 (1974) 1281-1284

Excitation pulse density dependence of IBL

D. I. Vaisburd et al, *High-energy solid-state electronics*, Izdatel'stvo Nauka, Novosibirsk, 1982. In Russian.



# The experimental facts about IBL in insulators

- Very fast decay:  $\tau < 10$  ps (R. Deich), must be around  $10^{-12}$  s.

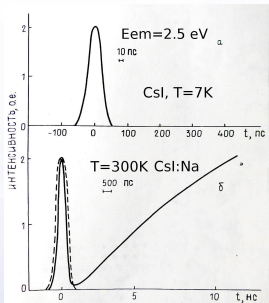


Figure: The IBL time shape at 2.5 eV of Csl and Csl:Na from Deich thesis and [2]. Excitation by electron beam, pulse width 50 ps

[2] R. Deich and M. Abdrakhmanov, NIM B 65 (1992) 525–529

# The experimental facts about IBL in insulators

- Alkali halides (D. Vaisburd ):
  - Structureless spectrum, terminated by fundamental absorption
  - Independence on temperature and impurity content
  - Quantum yield in KI about  $10^{-4}$

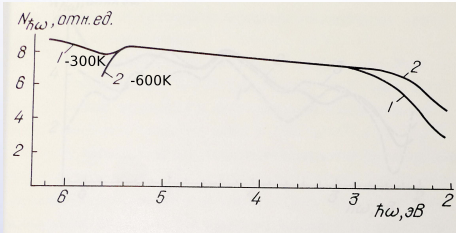


Рис. 1.4. Спектры люминесценции кристалла RbCl при наносекундном возбуждении плотным потоком электронов:  
 1 - 300 К, 2 - 600 К

The IBL spectra of RbCl, excited by electron beam (3ns)

D. I. Vaisburd et al, *High-energy solid-state electronics*, Izdatel'stvo Nauka, Novosibirsk, 1982. In Russian.

# The experimental facts about IBL in insulators

- Hole component spectrum reflects valence band structure, terminated by its width
- In alkali halides the e-IBL is 20–60 times more intense
- In wide-gap oxides and some other materials the h-IBL is dominating (A. Lushchik, F. Savihhin et al. )

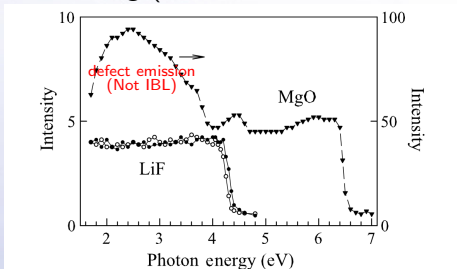


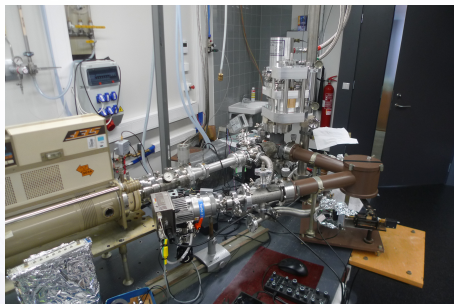
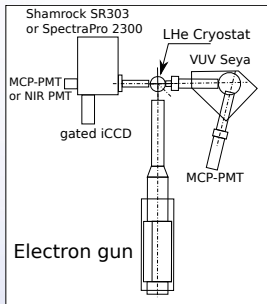
Fig. 7. The spectra of intraband luminescence ( $\tau < 2$  ns) measured for LiF at 80 (○) or 300 K (●●) and for a MgO crystal at 730 K (▼▼) under irradiation by single 300 keV electron pulses.

## Motivation for modern studies

- Remarkable advances in technical development:
  - pulsed excitation sources: fs lasers, ps x-ray and electrons, FEL
  - fast light detectors: MCP-PMT, SPAD and SiPM, Hybrid detectors, Streak cameras
- New application challenges: 10ps TOF-PET, GHz Xray cameras, future LHC pileup correction
- The search for materials with higher IBL yield



# The pulse cathodoluminescence setup in Tartu



- Electron energy 100–200 keV, pulse current up to 50 A/cm<sup>2</sup>
- **High resolution mode: 55 ps FWHM**
- Fast to slow emissions ratio (dynamic range up to seconds)
- Spectral range 0.75–10.6 eV (117–1650 nm)
- Temperature range 5.5–800 K

# New spectral features

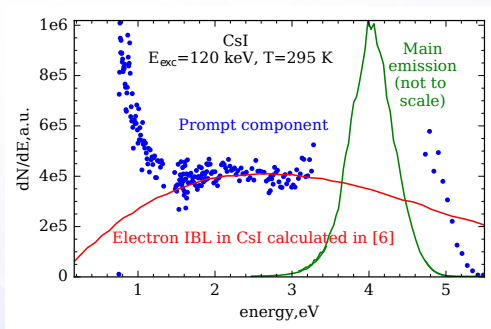
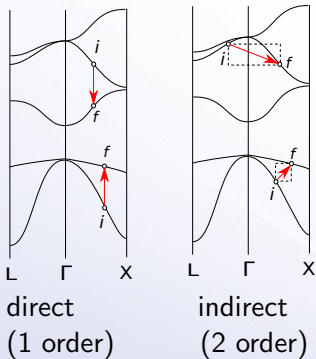
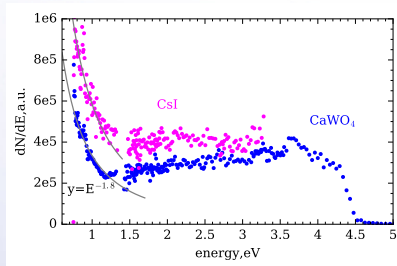


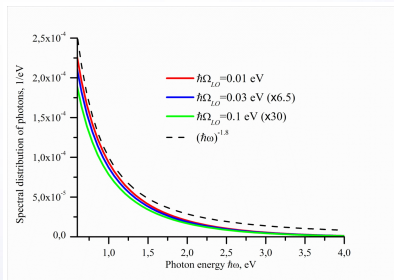
Figure: The types of radiative intraband transitions and IBL spectra of CsI

[6] D. I. Vaisburd, S. Kharitonova, Russian Physics Journal, 1997, 40:1037

# Experimental and theoretical 2-order spectrum of IBL



experimental



theoretical

Figure: Spectral distribution of the number of prompt photons emitted by sample during electron pulse. Normalized arbitrarily.

S.I. Omelkov, V. Nagirnyi, A.N. Vasil'ev, M. Kirm J. Lumin., 2016, 176, 309–317  
 A. N. Vasil'ev, R. V. Kirkin, Physics of Wave Phenomena, 2015, 23(3): 186

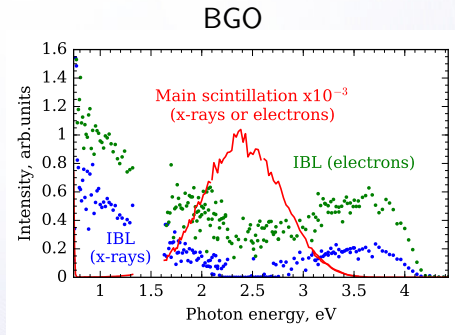
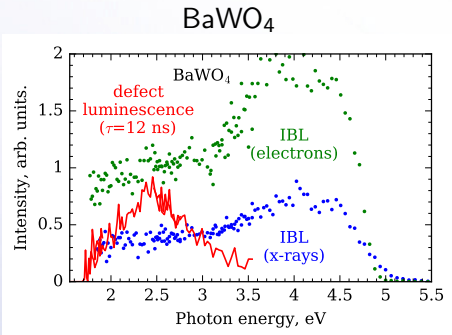


## 10-ps challenge

Question:

Can IBL be excited by single **x-ray** and  
511-keV  **$\gamma$ -quanta**?

# x-ray excited IBL of $\text{Bi}_4\text{Ge}_3\text{O}_{12}$ and $\text{BaWO}_4$



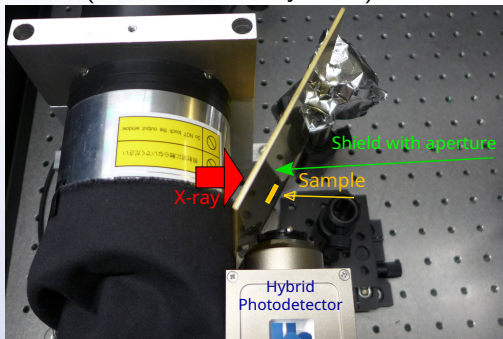
IBL spectra under electron beam and x-ray excitation, normalized to the same intensity of main scintillation band.

Electron energy: 80–110 keV; X-ray energy 10–80 keV

S.I. Omelkov et al J. Lumin., 2017, 191, 61–67

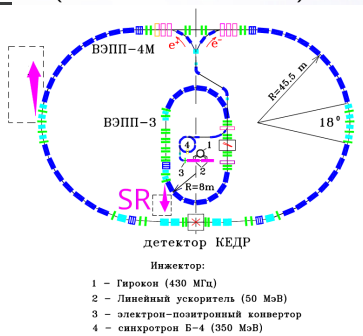
# IBL under x-ray excitation: nonproportionality effects?

XRL setup in CERN  
(Laser-excited xray tube)



3–40 keV max 10 keV  
Low power, no spectral resolution  
2 MHz repetition rate  
~100 ps FWHM time resolution

XRL setup on VEPP-3 ring  
(2 GeV, Novosibirsk)

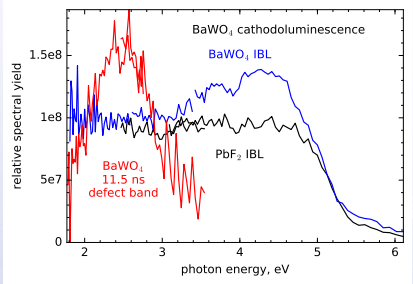


3–60 keV max 10 keV  
High power, used 55  $\mu\text{m}$  Cu  
filter 8.06 MHz repetition rate  
~1 ns FWHM time resolution

# IBL in BaWO<sub>4</sub>

Tartu

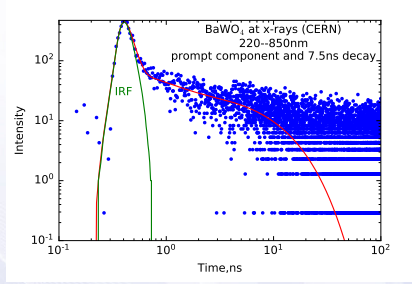
X-ray luminescence (10–80 keV)



$$\text{Yield(IBL)} = 2.2 \times \text{Yield(defect)}$$

CERN

X-ray  $\leq 40$  keV

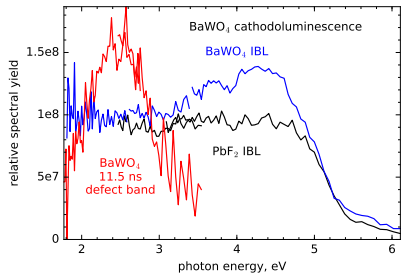


$$\text{Yield(IBL)} = 0.2 \times \text{Yield(defect)}$$

# IBL in BaWO<sub>4</sub>

Tartu

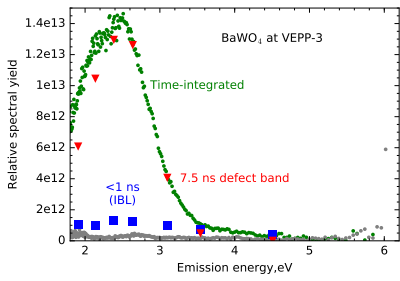
X-ray luminescence (10–80 keV)



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Novosibirsk

X-ray  $\leq 60$  keV (VEPP-3)



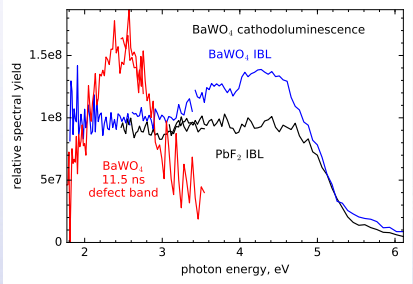
$$\text{Yield(IBL)} = 0.3 \times \text{Yield(defect)}$$



# IBL in BaWO<sub>4</sub>

Tartu

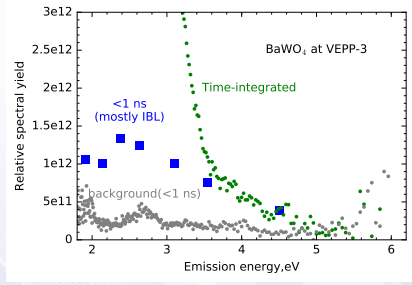
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Novosibirsk

X-ray  $\leq 60$  keV (VEPP-3)



$$\text{Yield(IBL)} = 0.3 \times \text{Yield(defect)}$$



## 10-ps challenge

Question:

What is the brightest IBL emitter?

# IBL spectral yield - binary compounds

120 keV 200 ps electron beam excitation

Highest phonon modes from Raman

Raman

scattering,  $\text{cm}^{-1}$ :

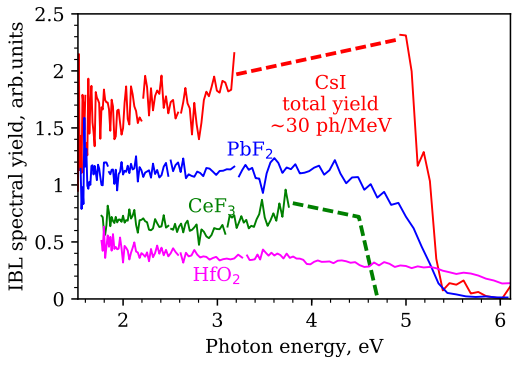
CsI: 90[1]

PbF<sub>2</sub>: 338[2]

CeF<sub>3</sub>: 396[3]

HfO<sub>2</sub>: 680[4]

Yield determined from spectra relative to LYSO:Ce



[1] S. Ganesan et al, *J. Phys. I*, 1965, 26(11): 639

[2] M. Dickens and M. Hutchings *J. Phys. C: Solid State Phys.*, 1978, 11: 461

[3] R.P. Bauman, S.P.S. Porto *Phys. Rev.*, 1967, 161(3): 842

[4] E. Anastassakis et al *J. Phys. Chem. Solids*, 1975, 36: 667

# Radiative lifetimes depend on band structure?

$$\eta = \frac{P_{rad}}{P_{nonrad}} \approx \frac{\tau_{nonrad}}{\tau_{rad}}$$

Depends on phonon spectrum

Depends on initial and final states

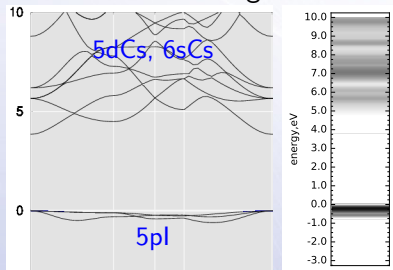
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Band structure fragment for CsI from AFlowLIB.org



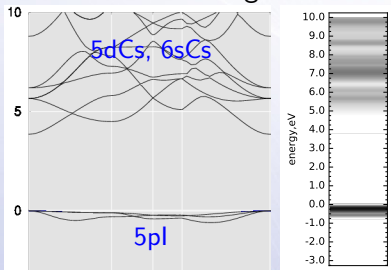
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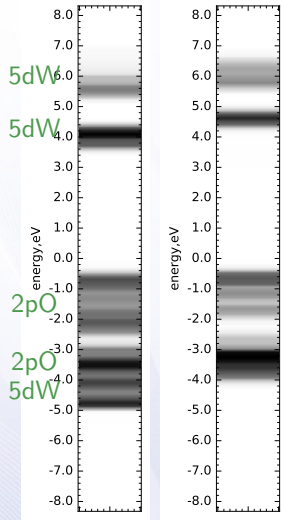
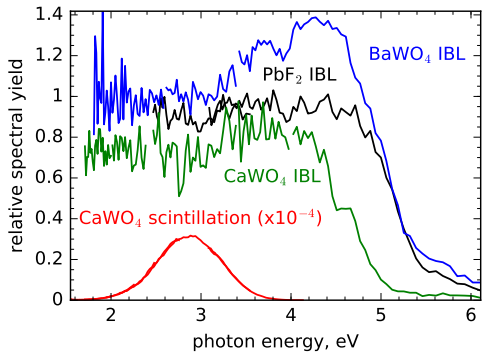
Band structure fragment for CsI from AFlowLIB.org



How to improve?

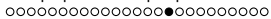
- Make use of hole transitions
- Diversify states (s,p,d,f)
- Increase DOS
- Include gaps in DOS

# IBL and band structure: tungstates

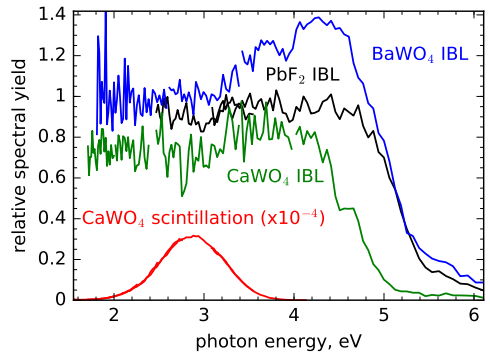


The IBL yields:  
 CaWO<sub>4</sub> - 13 ph/MeV  
 PbF<sub>2</sub> - 17 ph/MeV  
 BaWO<sub>4</sub> - 21 ph/MeV

Band structure from [Lacomba-Perales et al J. Appl. Phys. 110 043703 (2011)]



# IBL and band structure: tungstates



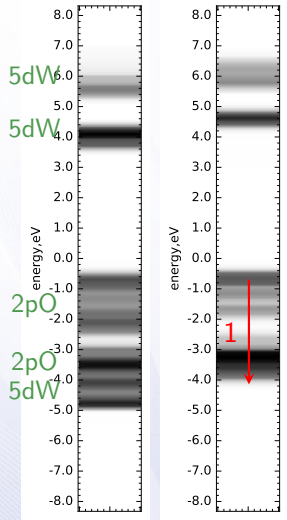
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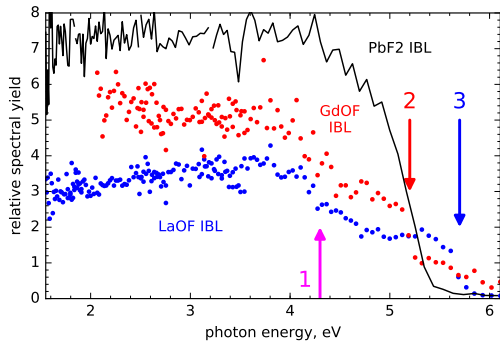


CaWO<sub>4</sub>

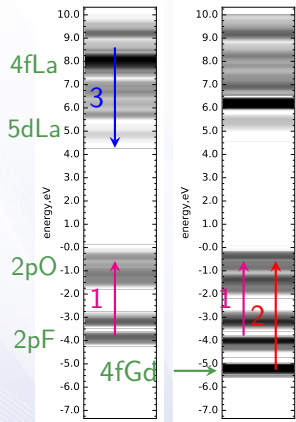
BaWO<sub>4</sub>



# IBL and band structure: rare-earth oxyfluorides



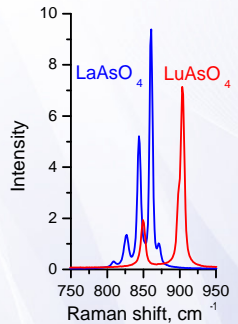
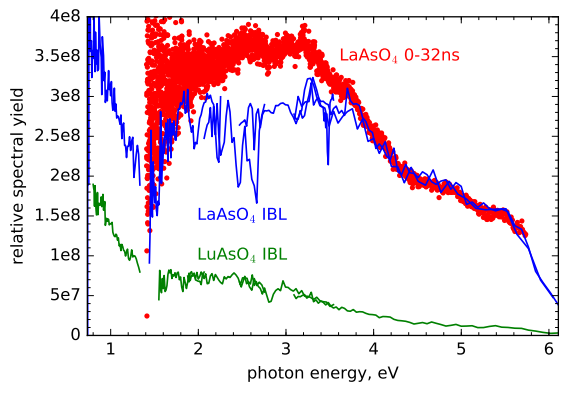
Band structure from AFlowLIB.org



LaOF

GdOF

# IBL and band structure: rare-earth arsenates



The IBL yields:  
**LaAsO<sub>4</sub> ≈ 25–30 ph/MeV**

More on IBL and phonons: S. Omelkov et al, J.Lumin 198 (2018) p260

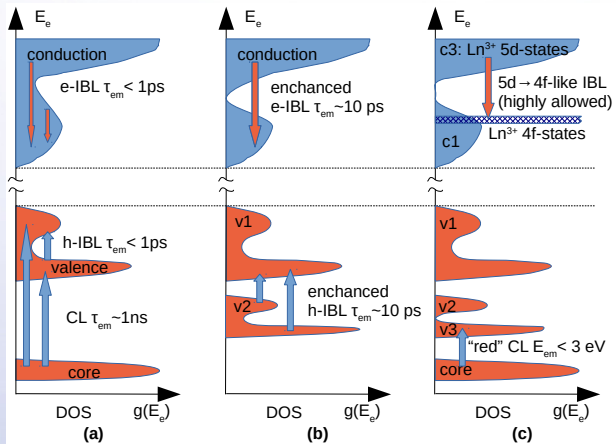


## 10-ps challenge

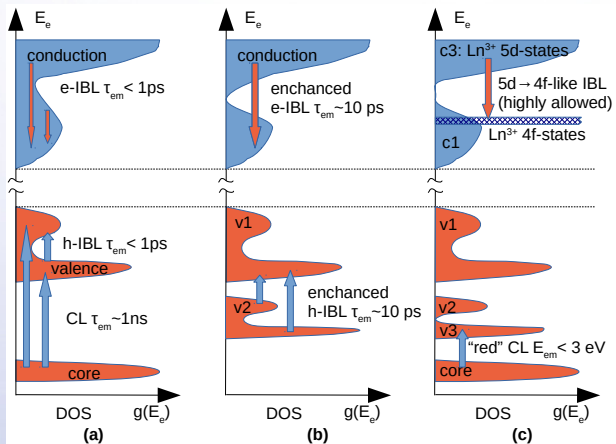
Question:

Is there a way to get more prompt photons?

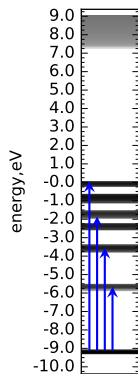
# Band structure engineering



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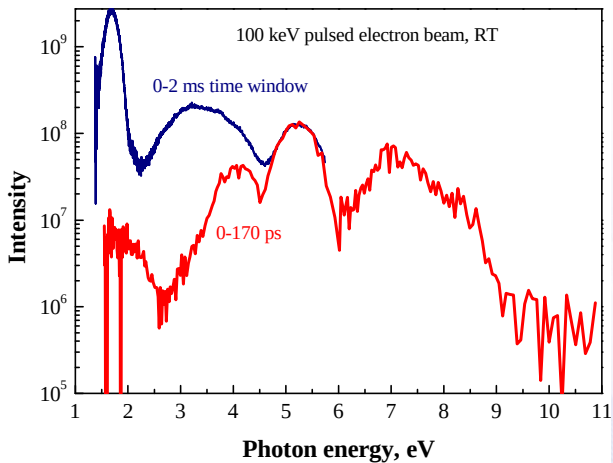


K<sub>2</sub>SiF<sub>6</sub>

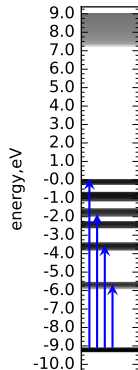


(AFlowLIB.org)

# Band structure engineering



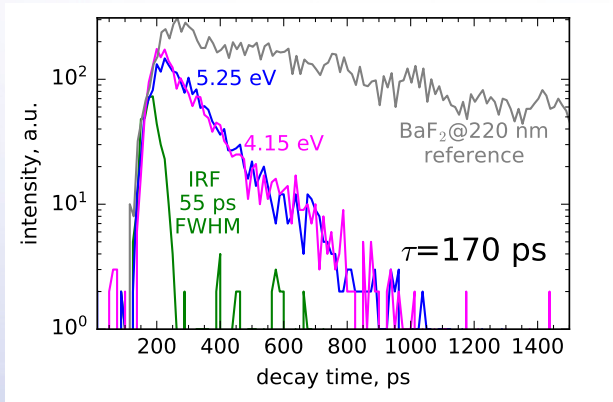
$K_2SiF_6$



(AFlowLIB.org)

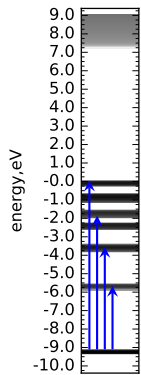
Spectrum of VUV, UV and red crossluminescence

# Band structure engineering



Decay of crossluminescence in  $K_2SiF_6$

$K_2SiF_6$



(AFlowLIB.org)



## 10-ps challenge

Question:

What IBL is good for?



# The prospects of hot intraband luminescence

- IBL rise time: femtoseconds
- IBL decay:  $<1\text{ps}$
- IBL yield: 30 ph/MeV (possibly more)

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Problem: we need a detector with same time resolution

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SPAD approached  **$7.8\text{ ps}$**  FWHM

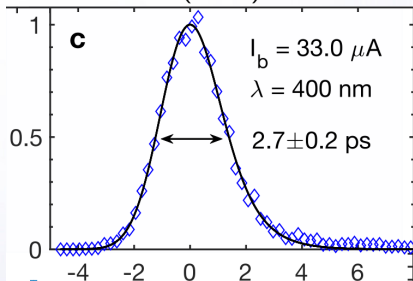
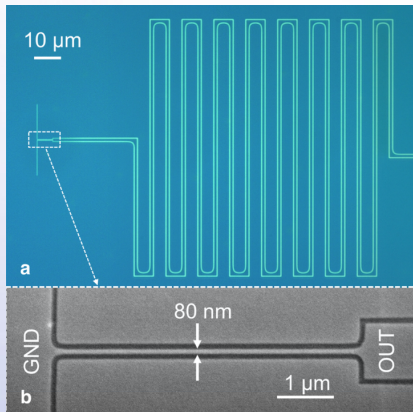
F. Nolet et al, Instruments 2018, 2, 19

Tynode-based PMT promises  **$<10\text{ps}$**

H. van der Graaf et al, NIM A 2017, 841, 148

# The prospects for hot intraband luminescence

## Superconductive nanowire single-photon detectors (2018)



- **SPTTR < 3 ps FWHM**
- PDP  $\approx 100\%$
- sensitive area  $0.08 \times 5 \mu\text{m}^2$
- cryogenic operation (0.9 K)

From arXiv:1804.06839 [physics.ins-det]

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- IBL has strong NIR component due to the phonon-assisted transitions
- IBL can be excited by single X-ray photons
- IBL seems to have strong nonproportionality
- IBL yield depends on phonon energies
- Best yield so far:  $\sim 30$  Ph/MeV  
(CsI and LaAsO<sub>4</sub>)

## New properties and prospects for hot intraband luminescence

- IBL has strong NIR component due to the phonon-assisted transitions
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- **Picosecond scintillation timing is possible**

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FAST  
Fast Advanced Scintillator Timing

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# Thank you for attention